

COMPLEMENTARY SILICON TRANSISTORS



# Central Semiconductor Corp.

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# DESCRIPTION:

The CENTRAL SEMICONDUCTOR 2N5172 and 2N6076 are complementary silicon small signal transistors designed for general purpose applications.

#### MARKING: FULL PART NUMBER

MAXIMUM RATINGS: (T <sub>A</sub> =25°C)	SYMBOL		UNITS
Collector-Base Voltage	V <sub>CBO</sub>	25	V
Collector-Emitter Voltage	VCEO	25	V
Emitter-Base Voltage	V <sub>EBO</sub>	5.0	V
Continuous Collector Current	۱ <sub>C</sub>	100	mA
Power Dissipation	PD	625	mW
Operating and Storage Junction Temperature	T <sub>J</sub> , T <sub>stg</sub>	-65 to +150	°C

#### **ELECTRICAL CHARACTERISTICS:** (T<sub>A</sub>=25°C unless otherwise noted)

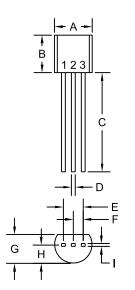
TEST CONDITIONS	MIN	TYP	MAX	UNITS
V <sub>CB</sub> =25V			100	nA
V <sub>CB</sub> =25V, T <sub>A</sub> =100°C			10	μA
V <sub>CE</sub> =25V			100	nA
V <sub>EB</sub> =5.0V (2N5172)			100	nA
V <sub>EB</sub> =3.0V (2N6076)			100	nA
I <sub>C</sub> =10mA	25			V
I <sub>C</sub> =10mA, I <sub>B</sub> =1.0mA			0.25	V
I <sub>C</sub> =10mA, I <sub>B</sub> =1.0mA			0.80	V
V <sub>CE</sub> =10V, I <sub>C</sub> =10mA	0.5		1.2	V
V <sub>CE</sub> =10V, I <sub>C</sub> =10mA	100		500	
V <sub>CE</sub> =10V, I <sub>C</sub> =10mA, f=1.0kHz	100		750	
V <sub>CB</sub> =5.0V, I <sub>C</sub> =2.0mA		200		MHz
V <sub>CB</sub> =10V, I <sub>E</sub> =0, f=1.0MHz	1.0		13	pF
	TEST CONDITIONS $V_{CB}=25V$ $V_{CE}=25V$ $V_{EB}=5.0V$ (2N5172) $V_{EB}=3.0V$ (2N6076) $I_{C}=10mA$ $I_{C}=10mA$ , $I_{B}=1.0mA$ $I_{C}=10mA$ , $I_{B}=1.0mA$ $V_{CE}=10V$ , $I_{C}=10mA$ $V_{CE}=10V$ , $I_{C}=10mA$ $V_{CE}=10V$ , $I_{C}=10mA$ $V_{CE}=10V$ , $I_{C}=10mA$ $V_{CE}=5.0V$ , $I_{C}=2.0mA$	TEST CONDITIONS       MIN $V_{CB}=25V$ $V_{CB}=25V$ $V_{CE}=25V$ $V_{CE}=25V$ $V_{EB}=5.0V$ (2N5172) $V_{EB}=3.0V$ (2N6076) $I_{C}=10mA$ 25 $I_{C}=10mA$ , $I_{B}=1.0mA$ 25 $V_{CE}=10V$ , $I_{C}=10mA$ 0.5 $V_{CE}=10V$ , $I_{C}=10mA$ , f=1.0kHz       100 $V_{CB}=5.0V$ , $I_{C}=2.0mA$ 100	$\begin{array}{c} \mbox{V}_{CB} = 25 \mbox{V}_{CB} = 25 \mbox{V}_{CE} = 25 \mbox{V}_{CE} = 25 \mbox{V}_{CE} = 25 \mbox{V}_{CE} = 5.0 \mbox{V}_{2N5172}) \mbox{V}_{EB} = 3.0 \mbox{V}_{2N6076}) \mbox{I}_{C} = 10 \mbox{M}_{A} \mbox{I}_{B} = 1.0 \mbox{m}_{A} \mbox{I}_{C} = 10 \mbox{m}_{A} \mbox{I}_{B} = 1.0 \mbox{m}_{A} \mbox{M}_{CE} = 10 \mbox{V}_{A} \mbox{I}_{C} = 10 \mbox{M}_{A} \mbox{I}_{C} = 10 \mbox{m}_{A} \mbox{I}_{C} = 10 \mbox{m}_{A} \mbox{I}_{C} = 10 \mbox{m}_{A} \mbox{m}_{B} = 1.0 \mbox{m}_{A} \mbox$	$\begin{array}{c c c c c c c c c c c c c c c c c c c $

R1 (7-February 2014)





#### COMPLEMENTARY SILICON TRANSISTORS



#### DIMENSIONS INCHES MILLIMETERS SYMBOL MIN MAX MIN MAX A (DIA) 0.175 0.205 4.45 5.21 В 0.170 0.210 4.32 5.33 С 0.500 12.70 --0.016 0.022 0.41 0.56 D Е 0.100 2.54 F 0.050 1.27 G 0.125 0.165 3.18 4.19 0.080 0.105 2.03 2.67 Н I. 0.015 0.38

TO-92 (REV: R1)

LEAD CODE:

1) Emitter

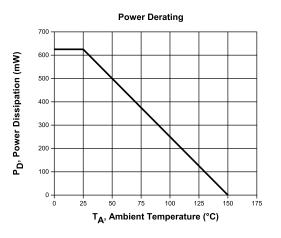
2) Collector

3) Base

R1

MARKING:

FULL PART NUMBER



R1 (7-February 2014)

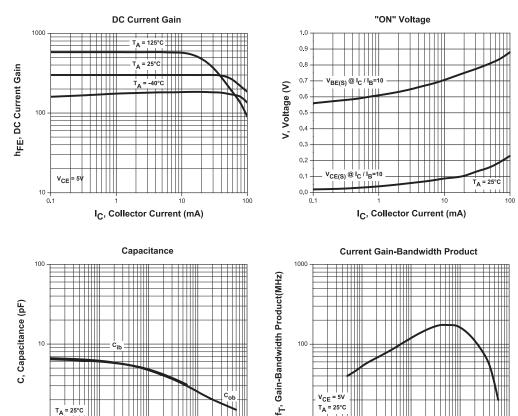
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#### **TO-92 CASE - MECHANICAL OUTLINE**



2N5172 NPN 2N6076 PNP

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V<sub>CE</sub> = 5V T<sub>A</sub> = 25°C

10 +

0.1

## NPN TYPICAL ELECTRICAL CHARACTERISTICS

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T<sub>A</sub> = 25°C

1 +

0.1

10

V<sub>R</sub>, Reverse Voltage (V)

100

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10

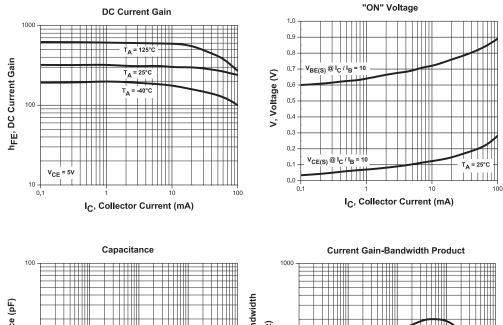
I<sub>C</sub>, Collector Current (mA)

100



2N5172 NPN 2N6076 PNP

COMPLEMENTARY SILICON TRANSISTORS



#### PNP TYPICAL ELECTRICAL CHARACTERISTICS

f<sub>T</sub>, Current Gain-Bandwidth C, Capacitance (pF) Product (MHz) 10 100 V<sub>CE</sub> = 5V T<sub>A</sub> = 25°C T<sub>A</sub> = 25°C 1111 1 + 10 + 0.1 10 100 0.1 10 100 V<sub>R</sub>, Reverse Voltage (V) I<sub>C</sub>, Collector Current (mA)

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# **OUTSTANDING SUPPORT AND SUPERIOR SERVICES**

#### **PRODUCT SUPPORT**

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- · Consolidated shipping options

#### **DESIGNER SUPPORT/SERVICES**

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2<sup>nd</sup> day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities

Special wafer diffusions

· Custom product packing

- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits

Custom bar coding for shipments

Custom product and package development

### **REQUESTING PRODUCT PLATING**

- 1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
- If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

#### CONTACT US

### **Corporate Headquarters & Customer Support Team**

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